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Kind regards,

Team Nexperia

BC848 series

30 V, 100 mA NPN general-purpose transistors

Rev. 07 — 17 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN general-purpose transistors in Surface Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	PNP		
	NXP	JEITA	JEDEC	complement
BC848B	SOT23	-	TO-236AB	BC858B
BC848W	SOT323	SC-70	-	BC858W

1.2 Features

- General-purpose transistors
- SMD plastic packages

1.3 Applications

■ General-purpose switching and amplification

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	30	V
I _C	collector current		-	-	100	mA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V};$ $I_{C} = 2 \text{ mA}$				
	BC848B		200	290	450	
	BC848W		110	-	800	



30 V, 100 mA NPN general-purpose transistors

Pinning information 2.

Table 3. Pinning

Tubic o.	9	
Pin	Description	Simplified outline Symbol
1	base	
2	emitter	3
3	collector	1—
		1 2 2 006aaa144 sym021

Ordering information 3.

Ordering information Table 4.

Type number	Package		
	Name	Description	Version
BC848B	-	plastic surface mounted package; 3 leads	SOT23
BC848W	SC-70	plastic surface mounted package; 3 leads	SOT323

Marking 4.

Product data sheet

Table 5. **Marking codes**

Type number	Marking code ^[1]
BC848B	1K*
BC848W	1M*

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	30	V
V_{CEO}	collector-emitter voltage	open base	-	30	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1]		
	SOT23		-	250	mW
	SOT323		-	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]			
	SOT23		-	-	500	K/W
	SOT323		-	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

30 V, 100 mA NPN general-purpose transistors

7. Characteristics

Table 8. Characteristics

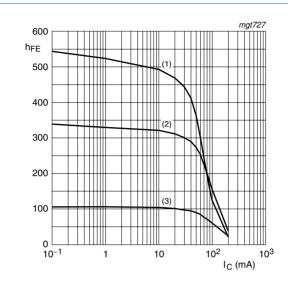
T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$		-	-	15	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{E} = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 10 μA		-	150	-	
		$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$					
		BC848B		200	290	450	
		BC848W		110	-	800	
V_{CEsat}		$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$		-	90	250	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[1]	-	200	600	mV
V_{BEsat}	base-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	[2]	-	700	-	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[2]	-	900	-	mV
V_{BE}	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	580	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	-	-	770	mV
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	2.5	3	pF
NF	noise figure	$V_{CE} = 5 \text{ V; } I_{C} = 200 \mu\text{A;}$ $R_{S} = 2 k\Omega; f = 1 k\text{Hz;}$ $B = 200 \text{ Hz}$		-	2	10	dB

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] V_{BEsat} decreases by approximately 1.7 mV/K with increasing temperature.

^[3] V_{BE} decreases by approximately 2 mV/K with increasing temperature.



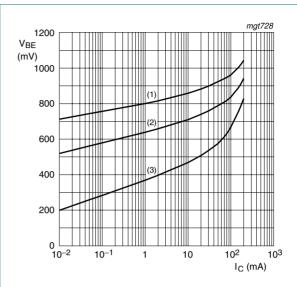
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 1. BC848B: DC current gain as a function of collector current; typical values



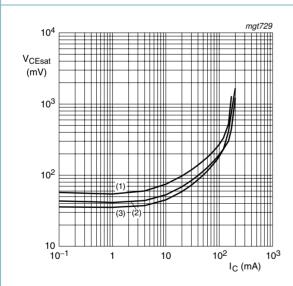
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 2. BC848B: Base-emitter voltage as a function of collector current; typical values



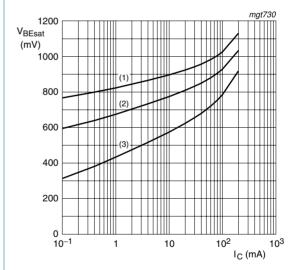
$$I_C/I_B = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \,^{\circ}C$$

Fig 3. BC848B: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

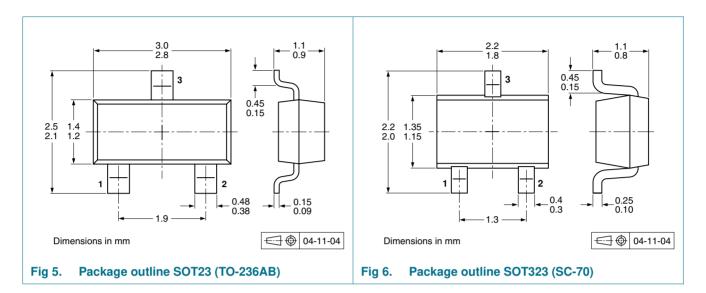
(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 4. BC848B: Base-emitter saturation voltage as a function of collector current; typical values

30 V, 100 mA NPN general-purpose transistors

Package outline 8.



Packing information 9.

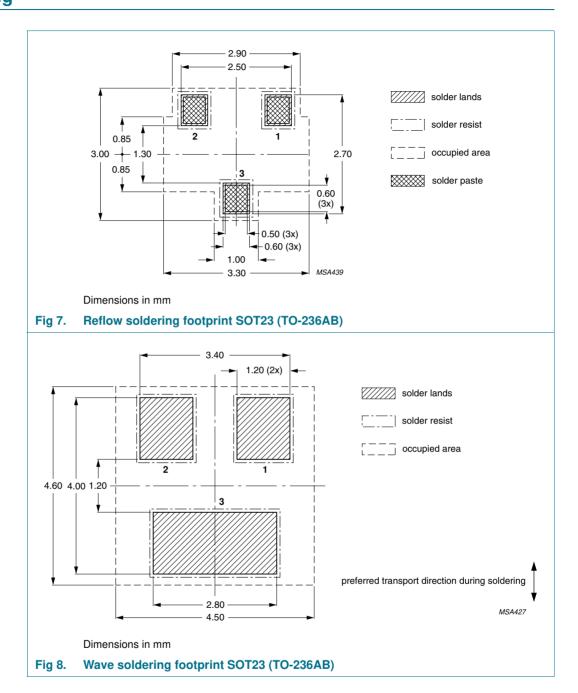
Product data sheet

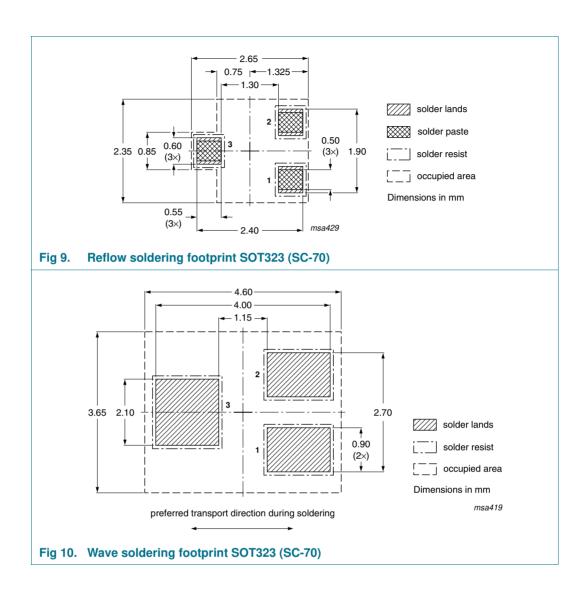
Table 9. **Packing methods** The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description Packing quan		quantity
			3000	10000
BC848B	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
BC848W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

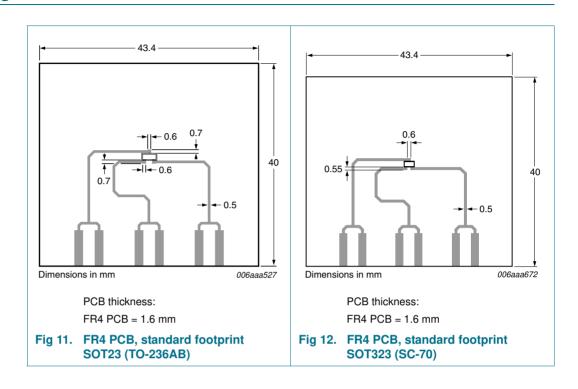
^[1] For further information and the availability of packing methods, see Section 14.

10. Soldering





11. Mounting



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12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC848_SER_7	20091117	Product data sheet	-	BC848_SER_6
Modifications:		t was changed to reflect the egal definitions and disclair		
	• Figure 9 "Reflo	w soldering footprint SOT3	23 (SC-70)": updated	
	• Figure 10 "Way	ve soldering footprint SOT3	323 (SC-70)": updated	
BC848_SER_6	20060203	Product data sheet	-	BC846_BC847_ BC848_5 BC846W_BC847W_ BC848W_4
BC846_BC847_BC848_5	20040206	Product specification	-	BC846_BC847_ BC848_4
BC846W_BC847W_ BC848W_4	20020204	Product specification	-	BC846W_847W_3

BC848 series

30 V, 100 mA NPN general-purpose transistors

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BC848 series

30 V, 100 mA NPN general-purpose transistors

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